NSN 5961-01-148-8504

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Diode Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-148-8504 **Inclosure Material:** Metal **Overall Length:** Between 0.518 inches and 0.523 inches **Overall Diameter:** 1.500 inches **Function For Which Designed:** Rectifier **Mounting Method:** Press fit **Features Provided:** Hermetically sealed case **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 300.0 repetitive peak reverse voltage **Current Rating Per Characteristic:** 400.00 amperes forward current, average **Maximum Operating Tempurature Per Measurement Point:** 200.0 degrees celsius junction **Test Data Document:** 80063-sm-a-743310 drawing (this is the basic governing drawing, such as a contractor drawing, original equipment manufacturer drawing, etc.; excludes any specification, standard or other document that may be referenced in a basic governing drawing) **Terminal Type And Quantity:** 2 ferrule Shelf Life: N/a **Unit Of Measure: Demilitarization:** No Fiig: